NSN 5962-01-073-8506

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View Online at https://aerobasegroup.com/nsn/5962-01-073-8506

Body Length:

Between 1.180 inches and 1.220 inches

Body Width:

Between 0.590 inches and 0.610 inches

Body Height:

Between 0.080 inches and 0.120 inches

Maximum Power Dissipation Rating:

1000.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/enable and w/decoded output and 3-state output and programmable and

programmed and w/strobe and expandable and bipolar and schottky and medium speed and w/buffered output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

60.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

30331-19-186f21 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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